

## CHAPTER – 1

### INTRODUCTION

#### 1.1 Semiconductor Curve tracer

A semiconductor curve tracer is a specialised piece of electronic test equipment used to analyze the characteristics of discrete semiconductor devices such as diodes, transistors, and thyristors. Based on an oscilloscope, the device also contains voltage and current sources that can be used to stimulate the device under test (DUT).

In our Project we have created a simple Output characteristic curve tracer for the BJT or MOSFET.

## CHAPTER - 2

### BJT:

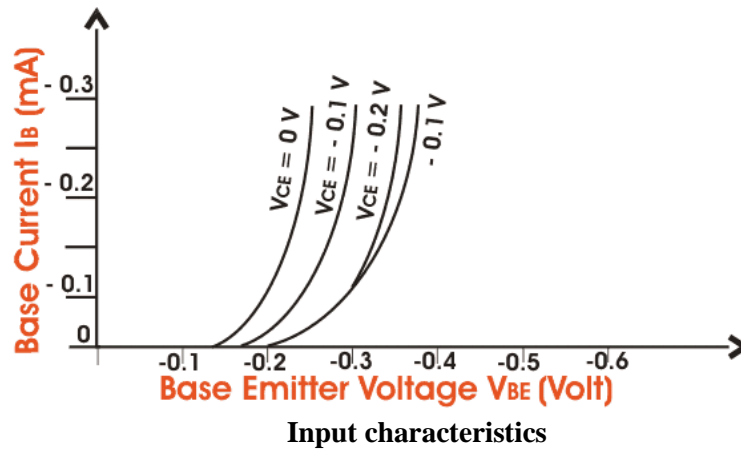
#### 2.1 Regions of operation:

Applied voltages	B-E junction bias (NPN)	B-C junction bias (NPN)	Mode (NPN)
$E < B < C$	Forward	Reverse	Forward-active
$E < B > C$	Forward	Forward	Saturation
$E > B < C$	Reverse	Reverse	Cut-off
$E > B > C$	Reverse	Forward	Reverse-active

#### 2.2 Common Emitter Characteristics:

##### 2.2.1 Input characteristics:

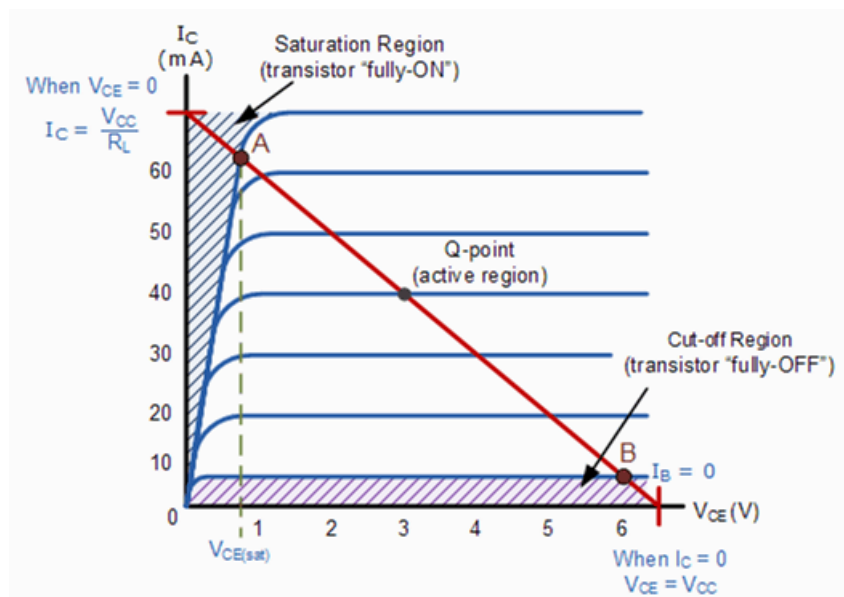
$I_B$  (Base Current) is the input current,  $V_{BE}$  (Base - Emitter Voltage) is the input voltage for CE (Common Emitter) mode. So, the input characteristics for CE mode will be the relation between  $I_B$  and  $V_{BE}$  with  $V_{CE}$  as parameter. The characteristics are shown below



The typical CE input characteristics are similar to that of a forward biased of p-n diode. But as  $V_{CB}$  increases the base width decreases.

### 2.2.2 Output characteristics:

Output characteristics for CE mode is the curve or graph between collector current ( $I_C$ ) and collector - emitter voltage ( $V_{CE}$ ) when the base current  $I_B$  is the parameter. The characteristics is shown below in the figure.

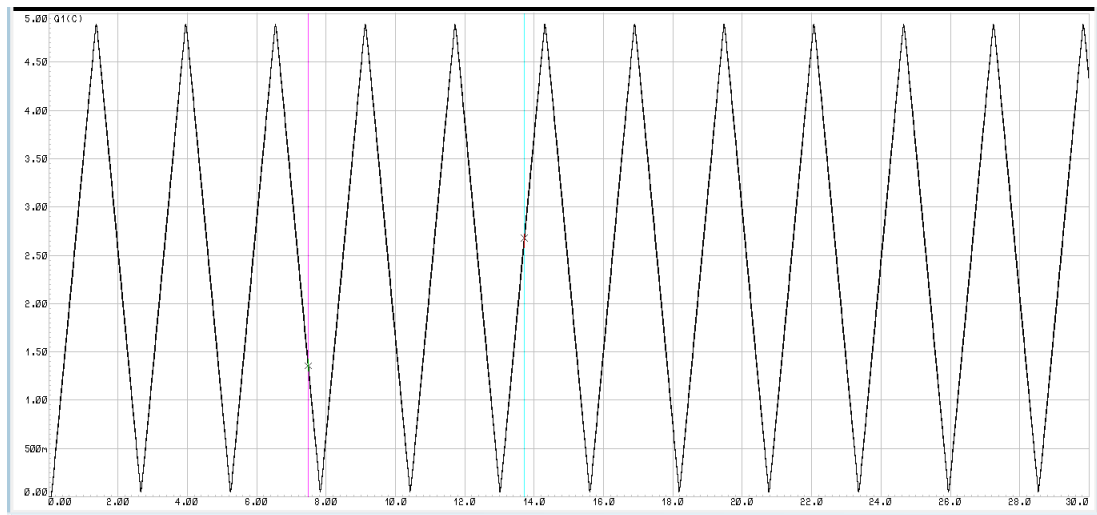


Like the output characteristics of common - base transistor CE mode has also three regions named (i) Active region, (ii) cut-off regions, (iii) saturation region. The active region has collector region reverse biased and the emitter junction forward biased. For cut-off region the emitter junction is slightly reverse biased and the collector current is not totally cut-off. And finally for saturation region both the collector and the emitter junction are forward biased.

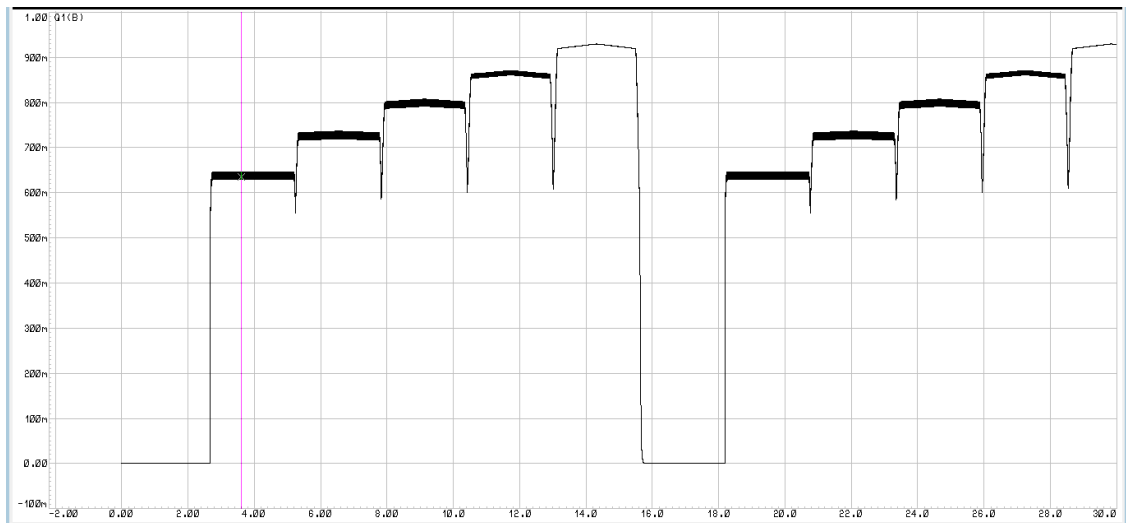
The Baud rate is set as 9600. The loop initiates only in arrival of the value 'H' from the Processing app. Digital pin5 is used to generate triangular wave. The PWM wave is increased in step of 4 from 0 to 255 and when it reaches 255 it is then decreased. At digital input pin 3 it is used to give it to the base. The PWM value is increased in 5 step for five output characteristic curves.

### Circuit Diagram Description:

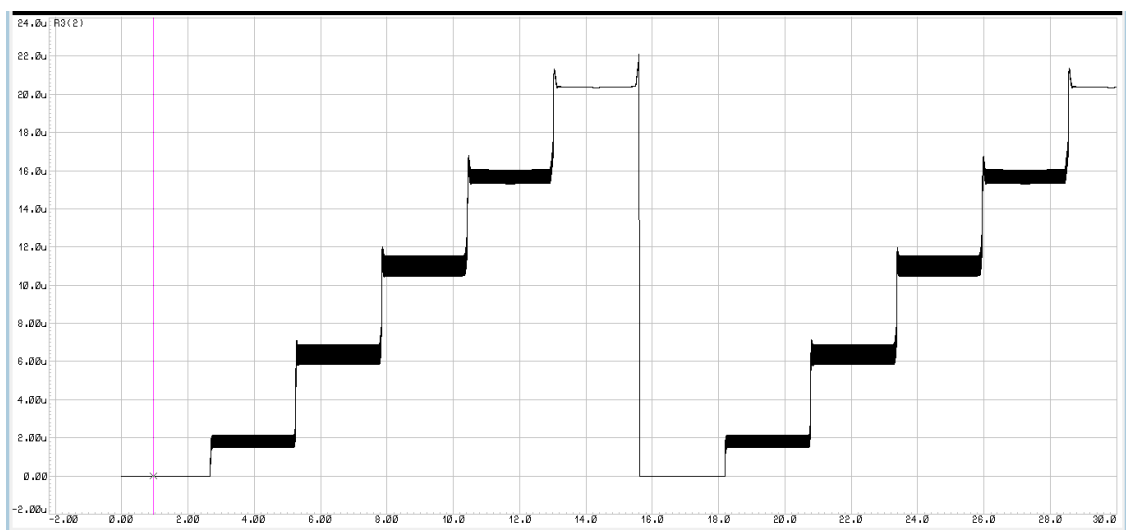
3



**Voltage at Collector Pin**



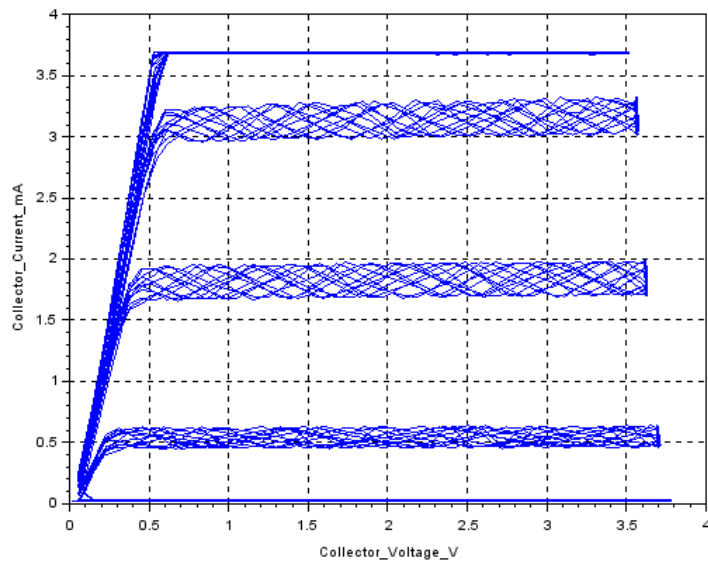
**Voltage at Base Terminal**



**Corresponding value of current**

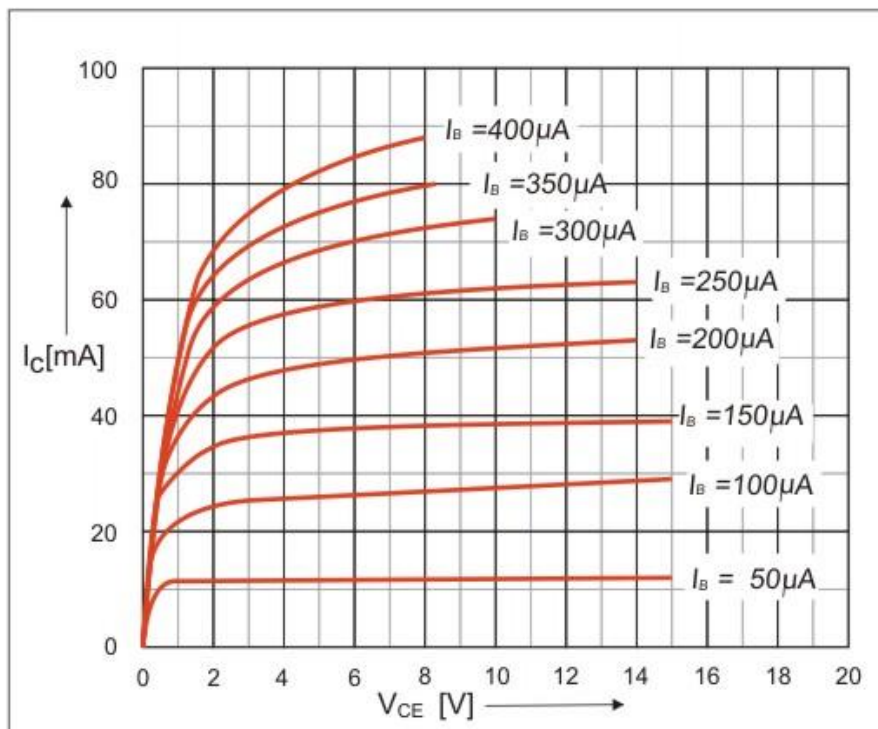
## CHAPTER - 4

### 4.1 BC547

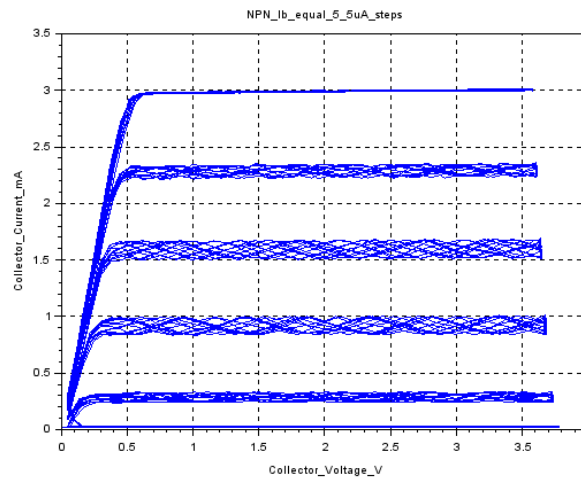


BC 547 Output characteristics

### BC 547 Characteristic curve from Datasheet



## 4.2 BD 139



BD 139 Output characteristics

## Chapter - 7

### Conclusion

Thus, we have the possibility to trace the characteristics of not only BJT but also several semiconductor devices at a time. This could be used in semiconductor industries.

### Reference:

- [https://www.google.co.in/amp/www.instructables.com/id/Arduino-BiCMOS-Curve-Tracer/%3famp\\_page=true](https://www.google.co.in/amp/www.instructables.com/id/Arduino-BiCMOS-Curve-Tracer/%3famp_page=true)
- <https://www.google.co.in/amp/s/www.elprocus.com/arduino-project-on-transistor-curve-tracer/amp/>
- <http://www.idea2ic.com/BiCmosCurveTracer/Arduino%2520BiCmos%2520Curve%2520Tracer.html>